ER1005 THRU ER110

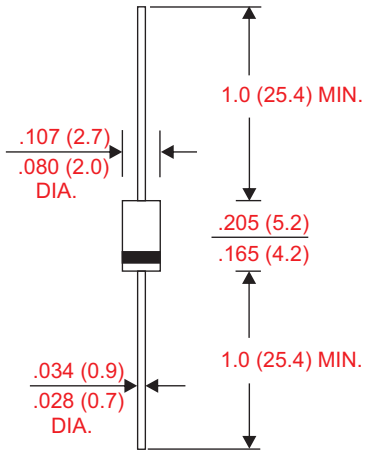
1 Amperes Leaded Type Super Fast Rectifiers
VOLTAGE : 50 TO 1000Volts

Features

- Axial lead type devices for through hole design.
- High current capability.
- Superfast recovery time for switching mode application.
- High surge current capability.
- Glass passivated chip junction.
- Suffix "G" indicates Halogen free parts, ex. ER1005G
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

Outline

DO-41(DO-204AL)



Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, DO-204AL / DO-41
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity : Color band denotes cathode end
- Weight : Approximated 0.33 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Parameter	Symbol	ER1005	ER101	ER102	ER104	ER106	ER108	ER110	UNIT
Making code		ER1005	ER101	ER102	ER104	ER106	ER108	ER110	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	
Maximum Forward Voltage	V_F	0.95			1.25	1.70			V
Operating Temperature	T_J	-50 ~ +150							°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current		I_O			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			30	A
Reverse current	$V_R = V_{RRM}$ $T_A = 25°C$	I_R			1.0	uA
	$V_R = V_{RRM}$ $T_A = 125°C$				300	
Maximum reverse recovery time	$I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$	T_{rr}			35	nS
Typical junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		50		pF

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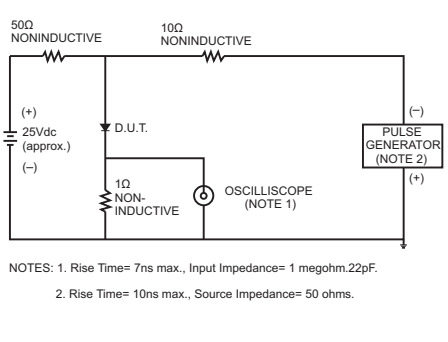
Rating and characteristic curves

FIG.1- TEST CIRCUIT DIAGRAM AND
REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

FIG.2-TYPICAL FORWARD CURRENT
DERATING CURVE

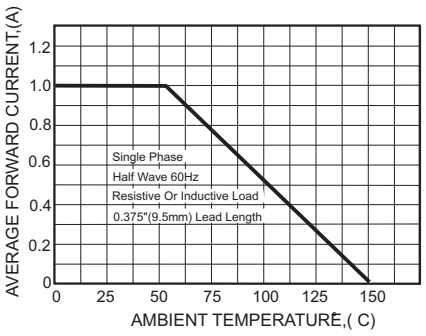


FIG.3-TYPICAL FORWARD
CHARACTERISTICS

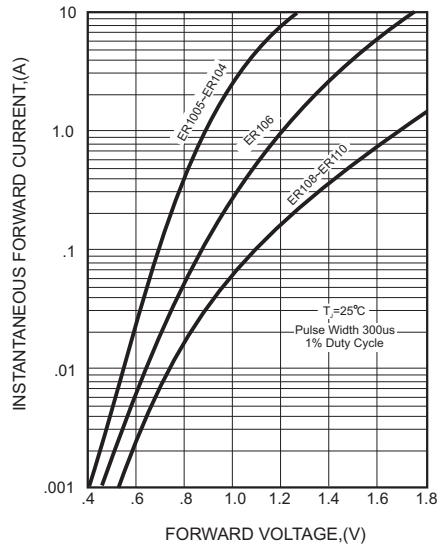


FIG.4-TYPICAL REVERSE
CHARACTERISTICS

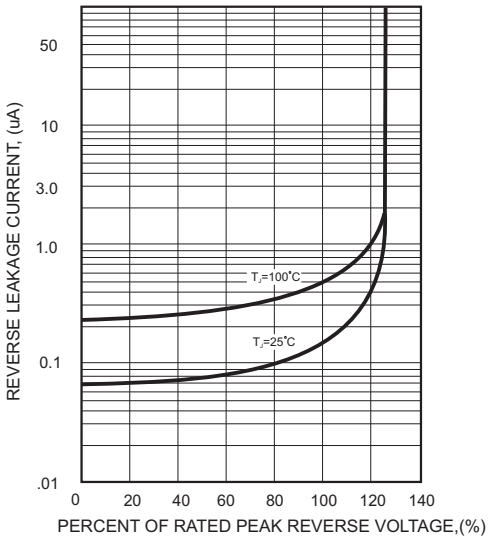


FIG.5-MAXIMUM NON-REPETITIVE

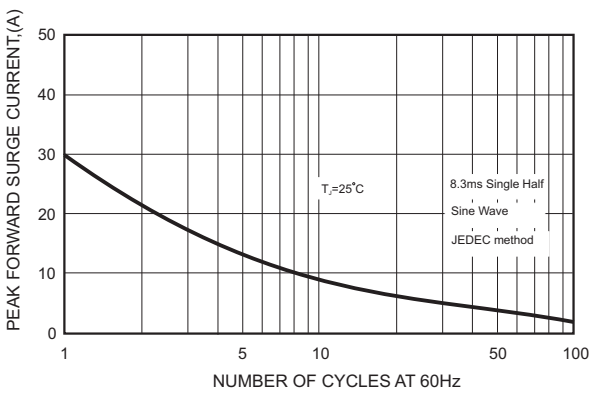


FIG.6-TYPICAL JUNCTION CAPACITANCE